## NSN 5961-01-507-3008

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-507-3008 **Inclosure Material:** Plastic **Overall Length:** Between 0.890 inches and 0.910 inches **Overall Height:** Between 0.262 inches and 0.282 inches **Overall Width:** Between 0.737 inches and 0.757 inches **End Application:** Arc 169; amplifier, radio frequency cage 00724 p/n 03-07520-001 **Mounting Facility Quantity:** 2 **Mounting Method: Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage/static/emitter open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 16.00 amperes source cutoff current **Power Rating Per Characteristic:** 270.0 watts small-signal input power, common-collector absolute **Product Name:** Npn silicon push-pull rf power transistor **Terminal Type And Quantity:** 8 beam lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: